# NSN 5961-01-118-6704

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## Inclosure Material:

Metal

**Overall Length:** 

1.252 inches

## **Overall Height:**

0.300 inches

## **Overall Width:**

0.700 inches

## **Mounting Facility Quantity:**

2

## Internal Configuration:

Junction contact

## Electrode Internally-electrically Connected To Case:

Collector

### **Mounting Method:**

Unthreaded hole

## Features Provided:

Hermetically sealed case

### Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

100.0 collector to base voltage, dc and 100.0 collector to emitter voltage/static/base open and 6.0 emitter to base voltage, instantaneous

## **Current Rating Per Characteristic:**

7.00 amperes source cutoff current and 1.00 amperes source cutoff current

### **Power Rating Per Characteristic:**

40.0 watts small-signal input power, common-collector absolute

### Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

### **Special Features:**

Junction pattern arrangement: npn

### Test Data Document:

07148-80918 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.;

excludes any specification, standard or other document that may be referenced in a basic governing drawing)

## Terminal Type And Quantity:

2 pin and 1 case

### Shelf Life:

N/a

## Unit Of Measure:

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## Demilitarization:

No

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